Photo DMOS-FET Relay

Description

The **LU834** is a miniature 1-Form B solid state relay in an 6 pin DIP package that employs optically coupled MOSFET technology to provide 3750V of input to output isolation. The optically coupled input is controlled by a highly efficient GaAlAs infrared LED and MOS FETs on the output side. .

Features

- Low driver power requirements (TTL/CMOS Compatible)
- Contact form: Normally-On (1b)
- Load voltage: 60V max.
- On-Resistance: 3Ω max.
- 3750 Vrms Input/Output isolation
- Tape & Reel version available

Applications

- Telecommunications (PC, Electronic notepad)
- Measuring and Testing equipment
- Industrial control
- Security equipments
- High speed inspection machine

Outline Dimensions

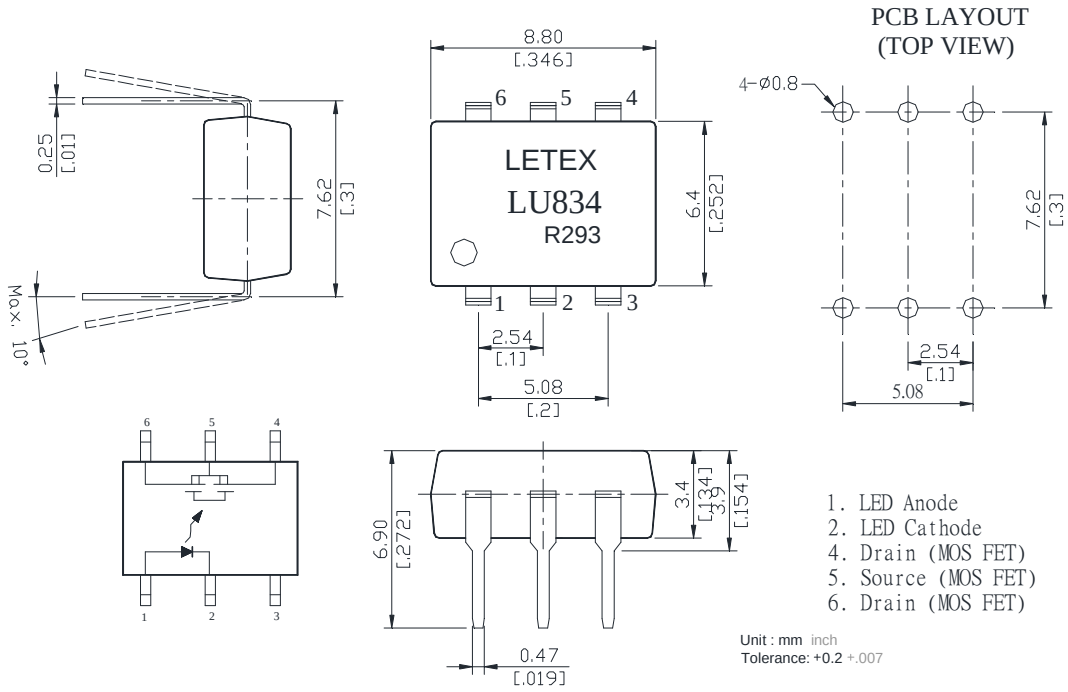


Photo DMOS-FET Relay Specifications

Part Name: LU834

(Load voltage: 60V / Load current: 500mA)

Absolute Maximum Ratings (Ambient Temperature: 25℃)

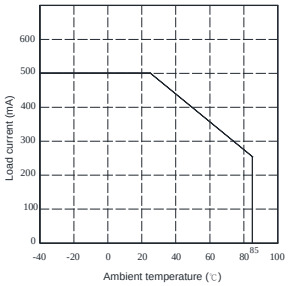
Item		Symbol	Value	Units	Note
Input	Continuous LED Current	I_F	50	mA	
	Peak LED Current	I_{FP}	500	mA	f=100Hz, duty=1%
	LED Reverse Voltage	V_R	5	V	
	Input Power Dissipation	P_{In}	75	mW	
Output	Load Voltage	V_L	60	V(AC peak or DC)	
	Load Current	I_L	500	mA	
	Peak Load Current	I_{Peak}	0.6	A	1ms(1 pulse)
	Output Power Dissipation	P_{out}	300	mW	
Total Power Dissipation		P_T	350	mW	
I/O Breakdown Voltage		$V_{I/O}$	3750	Vrms	RH=60%, 1min
Operating Temperature		Topr	-40 to +85	℃	
Storage Temperature		Tstg	-40 to +100	℃	
Pin Soldering Temperature		Tsol	260	℃	10 sec max.

Electrical Specifications (Ambient Temperature: 25℃)

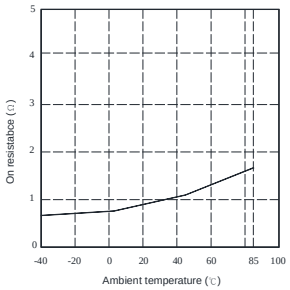
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	V_F		1.2	1.4	V	IF=10mA
	Operation LED Current	IFon		0.5	3.0	mA	
	Recovery LED Current	IFoff	0.1	0.4		mA	
	Recovery LED Voltage	VFoff	0.5			V	
Output	On-Resistance	Ron		1	3	Ω	IF=0mA,IL=50mA, Time to flow is within 1 sec.
	Off-State Leakage Current	ILeak			1	uA	IF=5mA,VL=60V
	Output Capacitance	Cout		165		pF	IF=5mA,VL=0, f=1MHz
Transmission	Turn-On Time	Ton		0.2	1.0	ms	IF=5mA, IL=50mA
	Turn-Off Time	Toff		0.5	3.0	ms	
Coupled	I/O Isolation Resistance	$R_{I/O}$	10^{10}			Ω	DC500V
	I/O Capacitance	$C_{I/O}$		0.8		pF	f=1MHz

Reference Data

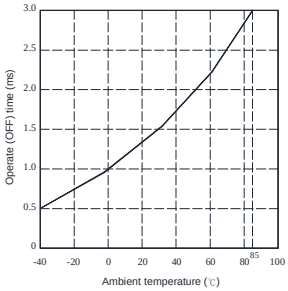
Load current Vs.
Ambient temperature



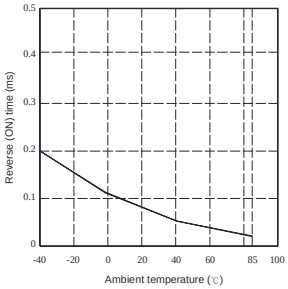
On resistance Vs.
Ambient temperature



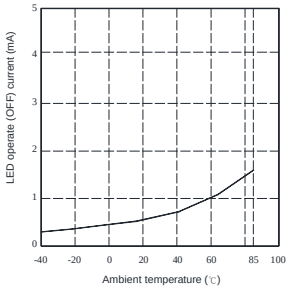
Operate (OFF) time Vs.
Ambient temperature



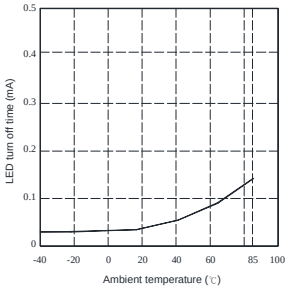
Reverse (ON) time Vs.
Ambient temperature



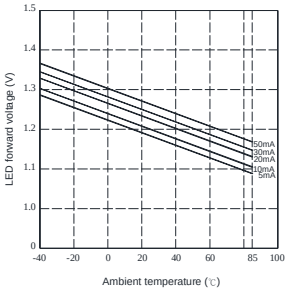
LED operate (OFF) current Vs.
Ambient temperature



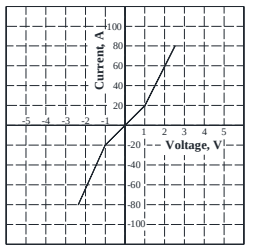
LED turn off current Vs.
Ambient temperature



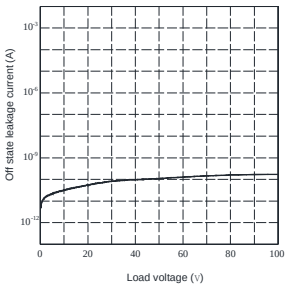
LED forward voltage Vs.
Ambient temperature



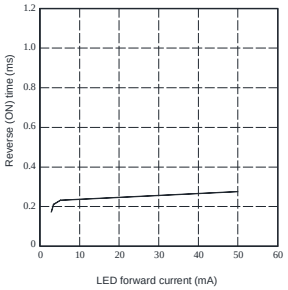
Voltage Vs. currennt characteristics
of output at MOS portion



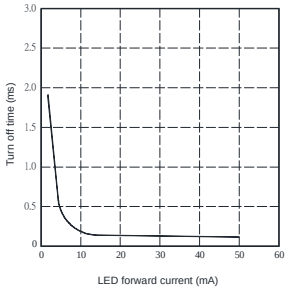
Off state leakage current Vs.
Load voltage characteristics



LED foward current Vs.
Reverse (ON) time characteristics



LED foward current Vs.
Operate (OFF) time characteristics



Applied voltage Vs.
output capacitance characteristics